

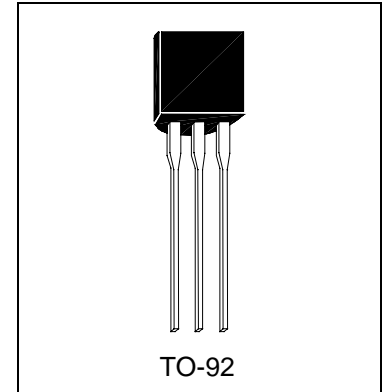


HA3669

NPN EPITAXIAL PLANAR TRANSISTOR

Description

The HA3669 is designed for using in power amplifier applications, power switching application.



Absolute Maximum Ratings (Ta=25°C)

- Maximum Temperatures
 Tstg Storage Temperature -55 ~ +150 °C
 Tj Junction Temperature +150 °C
- Maximum Power Dissipation
 Total Power Dissipation (Ta=25°C) 750 mW
- Maximum Voltages and Currents
 BVCBO Collector to Base Breakdown Voltage 80 V
 BVCEO Collector to Emitter Breakdown Voltage 80 V
 BVEBO Emitter to Base Emitter Breakdown Voltage 5 V
 IC Collector Current (DC) 2 A

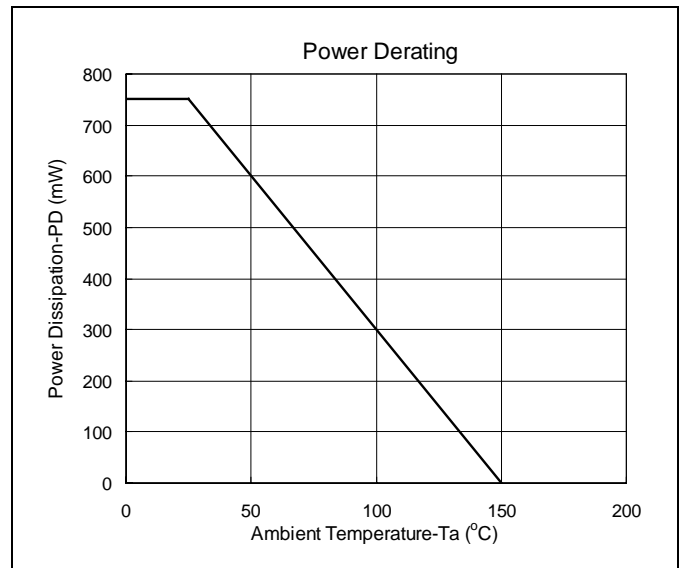
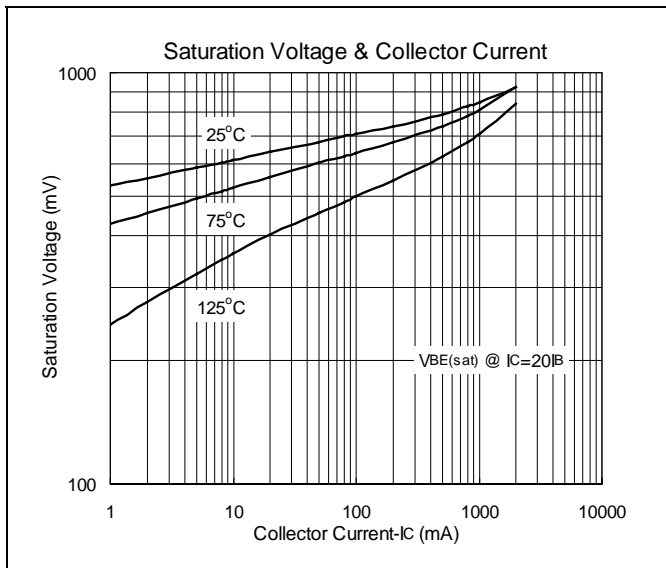
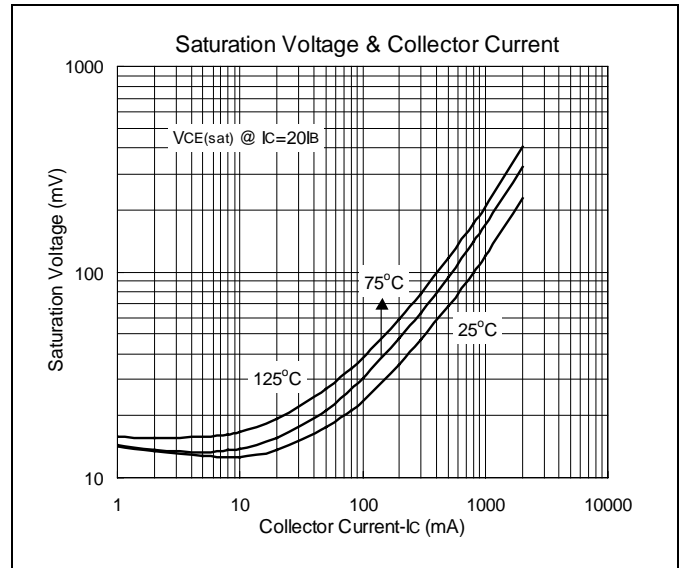
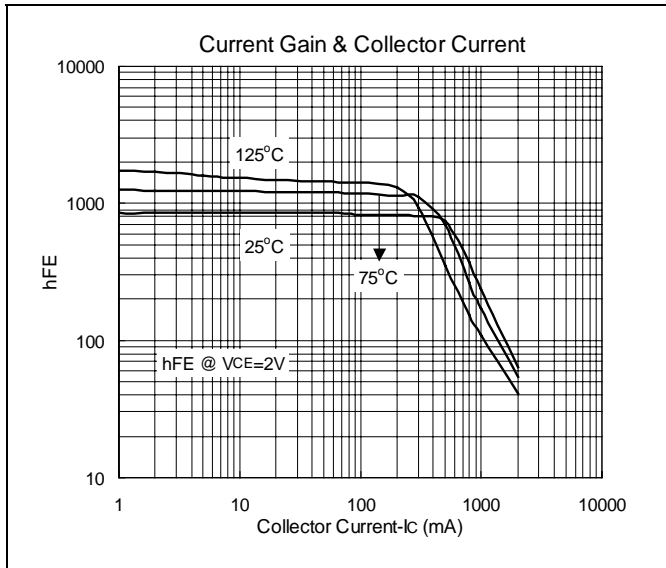
Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BVCBO	80	-	-	V	IC=100uA
BVCEO	80	-	-	V	IC=10mA
BVEBO	5	-	-	V	IE=100uA
ICBO	-	-	1000	nA	VCB=80V
IEBO	-	-	1000	nA	VEB=5V
*VCE(sat)	-	0.15	0.5	V	IC=1A, IB=50mA
*VBE(sat)	-	0.9	1.2	V	IC=1A, IB=50mA
*hFE	240	-	-		VCE=2V, IC=500mA
fT	-	100	-	MHz	VCE=2V, IC=500mA
Cob	-	30	-	pF	VCB=10V, f=1MHz
Ton	-	0.2	-	uS	IB1=-IB2=50mA, Duty Cycle≤1%
Tstg	-	1.0	-	uS	
Tf	-	0.2	-	uS	

*Pulse Test: Pulse Width ≤380us, Duty Cycle≤2%

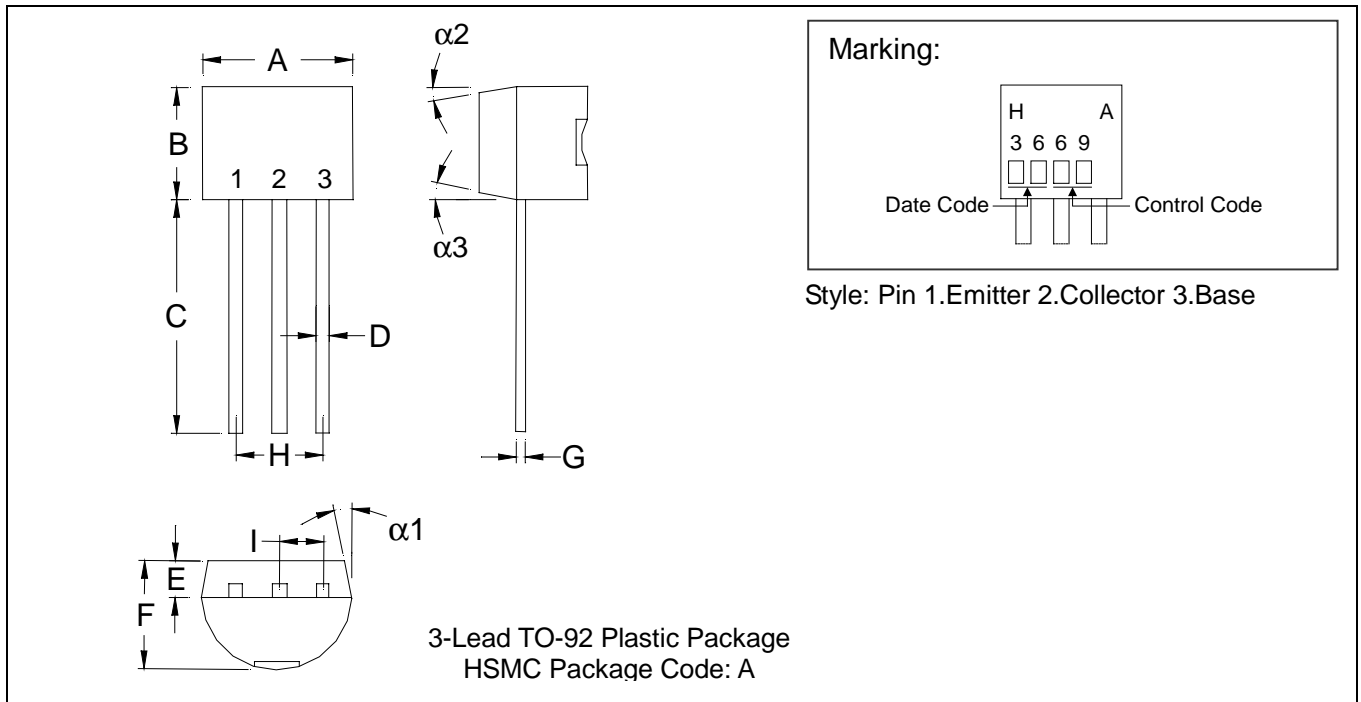


Characteristics Curve





TO-92 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1704	0.1902	4.33	4.83	G	0.0142	0.0220	0.36	0.56
B	0.1704	0.1902	4.33	4.83	H	-	*0.1000	-	*2.54
C	0.5000	-	12.70	-	I	-	*0.0500	-	*1.27
D	0.0142	0.0220	0.36	0.56	$\alpha 1$	-	*5°	-	*5°
E	-	*0.0500	-	*1.27	$\alpha 2$	-	*2°	-	*2°
F	0.1323	0.1480	3.36	3.76	$\alpha 3$	-	*2°	-	*2°

- Notes:**
- 1.Dimension and tolerance based on our Spec. dated Apr. 25,1996.
 - 2.Controlling dimension: millimeters.
 - 3.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 - 4.If there is any question with packing specification or packing method, please contact your local HSMC sales office.

Material:

- Lead: 42 Alloy; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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